



Quad SPST CMOS Analog Switches

APPLICATIONS

- Audio switching
- Battery powered systems
- Data acquisition
- Sample-and-hold circuits
- Telecommunication systems
- Automatic test equipment
- Single supply circuits
- Hard disk drives

DESCRIPTION

The DG444, DG445 monolithic quad analog switches are designed to provide high speed, low error switching of analog signals. The DG444 has a normally closed function. The DG445 has a normally open function. Combining low power (22 nW, typ) with high speed (t_{ON}: 120 ns, typ.), the DG444, DG445 are ideally suited for upgrading DG211, DG212 sockets. Charge injection has been minimized on the drain for use in sample-and-hold circuits.

To achieve high-voltage ratings and superior switching performance, the DG444, DG445 are built on Vishay Siliconix's high-voltage silicon-gate process. An epitaxial layer prevents latchup.

Each switch conducts equally well in both directions when on, and blocks input voltages to the supply levels when off.

FEATURES

• Low on-resistance: 50 Ω

Low leakage: 80 pA

Low power consumption: 22 nW

Fast switching action - t_{ON}: 120 ns Low charge injection

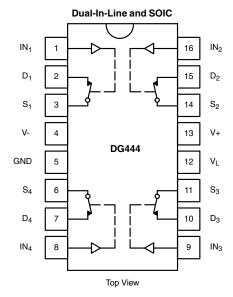
DG211, DG212 upgrades

• TTL/CMOS logic compatible

BENEFITS

- · Low signal errors and distortion
- Reduced power supply requirements
- Faster throughput
- Improved reliability
- Reduced pedestal errors
- Simple interfacing

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE							
Logic	DG444	DG445					
0	On	Off					
1	Off	On					

Logic "0" ≤ 0.8 V Logic "1" ≥ 2.4 V

ORDERING INFORMATION						
Temp. Range Package Part Number						
	16-pin plastic DIP	DG444DJ				
- 40 °C to 85 °C	10-pin plastic Dii	DG445DJ				
- 40 0 10 85 0	16-pin narrow SOIC	DG444DY				
	10-piii fiaitow 3010	DG445DY				

Document Number: 70054 S11-0984-Rev. G, 23-May-11



ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)						
Parameter		Limit	Unit			
V+ to V-		44				
GND to V-		25				
V _L		(GND - 0.3) to (V+) + 0.3	V			
Digital Inputs ^a , V _S , V _D		(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first				
Continuous Current (Any Terminal)		30	mA			
Current, S or D (Pulsed at 1 ms, 10	% Duty Cycle)	100	liiA			
Storage Temperature		- 65 to 125	°C			
	16-Pin Plastic DIP ^c	450	mW			
Power Dissipation (Package) ^b	16-Pin Narrow Body SOIC ^d	25 (GND - 0.3) to (V+) + 0.3 (V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first 30 100 - 65 to 125	T mvv			

Notes:

- a. Signals on S_X , D_X , or IN_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings. b. All leads welded or soldered to PC board.
- c. Derate 6 mW/°C above 75°C.
- d. Derate 8 mW/°C above 75°C.

		Test Conditions				D Suffix		
		Unless Otherwise Specified	d		- 40	°C °C to 8	5 °C	
		V+ = 15 V, V- = -15 V						
Parameter	Symbol	$V_L = 5 \text{ V}, V_{IN} = 2.4 \text{ V}, 0.8 \text{ V}^{e}$)	Temp.a	Min. ^b	Typ. ^c	Max. ^b	Unit
Analog Switch								
Analog Signal Range ^d	V _{ANALOG}			Full	- 15		15	V
Drain-Source On-Resistance	R _{DS(on)}	$I_S = -10 \text{ mA}, V_D = \pm 8.5 \text{ V}$ V+ = 13.5 V V- = -13.5 V		Room Full		50	85 100	Ω
Oli-Resistance		V+ = 13.5 V V- = - 13.5 V		Room	- 0.5	± 0.01	0.5	
	I _{S(off)}	V+ = 16.5, V- = - 16.5 V		Full	- 0.5 - 5	± 0.01	5	
Switch Off Leakage Current	I _{D(off)}	$V_D = \pm 15.5 \text{ V}, V_S = \pm 15.5 \text{ V}$	′	Room Full	- 0.5 - 5	± 0.01	0.5 5	nA
Channel On Leakage Current	I _{D(on)}	V+ = 16.5 V, V- = -16.5 V $V_S = V_D = \pm 15.5 \text{ V}$		Room Full	- 0.5 - 10	± 0.08	0.5 10	
Digital Control	l l	<u> </u>					l	
Input Current V _{IN} Low	I _{IL}	V_{IN} under test = 0.8 V All Other = 2.4 V		Full	- 500	- 0.01	500	
Input Current V _{IN} High	I _{IH}	V _{IN} under test = 2.4 V All Other = 0.8 V		Full	- 500	0.01	500	nA
Dynamic Characteristics							L	
Turn-On Time	t _{ON}	$R_I = 1 \text{ k}\Omega, C_I = 35 \text{ pF}$		Room		120	250	
Turn-Off Time	t	$V_S = \pm 10 \text{ V, See Figure 2}$	DG444	Room		110	140	ns
Turn-On Time	t _{OFF}	vg = ± 10 v, occ riguic z	DG445	Room		160	210	
Charge Injection ^e	Q	$C_L = 1 \text{ nF, } V_S = 0 \text{ V}$ $V_{gen} = 0 \text{ V, } R_{gen} = 0 \Omega$		Room		- 1		рС
Off Isolation ^e	OIRR	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$		Room		60		i.
Crosstalk (Channel-to-Channel) d	X _{TALK}			Room		100		dB
Source Off Capacitance	C _{S(off)}	f = 1 MHz		Room		4		pF
Drain Off Capacitance	C _{D(off)}			Room		4		
Channel On Capacitance	C _{D(on)}	$V_{ANALOG} = 0 V$		Room		16		



SPECIFICATIONS for Dual Supplies							
		Test Conditions Unless Otherwise Specified V+ = 15 V, V- = - 15 V		D Suffix - 40 °C °C to 85 °C			
Parameter	Symbol	$V_L = 5 \text{ V}, V_{IN} = 2.4 \text{ V}, 0.8 \text{ V}^e$	Temp.a	Min.b	Typ. ^c	Max. ^b	Unit
Power Supplies							
Positive Supply Current	l+		Room Full		0.001	1 5	
Negative Supply Current	l-	V+ = 16.5 V, V- = - 16.5 V	Room Full	- 1 - 5	- 0.0001		
Logic Supply Current	Ι _L	$V_{IN} = 0 \text{ or } 5 \text{ V}$	Room Full		0.001	1 5	μΑ
Ground Current	I _{GND}		Room Full	- 1 - 5	- 0.001		

SPECIFICATIONS for Unipolar Supplies							
		Test Conditions Unless Otherwise Specified		Limits - 40 °C °C to 85 °C			
Parameter	Symbol	V+ = 12 V, V- = 0 V $V_L = 5 V, V_{IN} = 2.4 V, 0.8 V^e$	Temp. ^a	Min.b	Typ. ^c	Max. ^b	Unit
Analog Switch							
Analog Signal Range ^d	V _{ANALOG}		Full	0		12	V
Drain-Source On-Resistance ^d	R _{DS(on)}	I_S = - 10 mA, V_D = 3 V, 8 V V+ = 10.8 V, V_L = 5.25 V	Room Full		100	160 200	Ω
Dynamic Characteristics					l	I.	
Turn-On Time	t _{ON}	$R_L = 1 \text{ k}\Omega, C_L = 35 \text{ pF}, V_S = 8 \text{ V}$	Room		300	450	no
Turn-Off Time	t _{OFF}	See Figure 2	Room		60	200	ns
Charge Injection	Q	$C_L = 1 \text{ nF, } V_{gen} = 6 \text{ V, R}_{gen} = 0 \Omega$	Room		2		рC
Power Supplies			•				
Positive Supply Current	l+	V+ = 13.2 V, V _{IN} = 0 or 5 V	Room Full		0.001	1 5	
Negative Supply Current	I-	V _{IN} = 0 or 5 V	Room Full	- 1 - 5	- 0.0001		
Logic Supply Current	ΙL	V _L = 5.25 V, V _{IN} = 0 or 5 V	Room Full		0.001	1 5	μΑ
Ground Current	I _{GND}	V _{IN} = 0 or 5 V	Full	- 1 - 5	- 0.001		

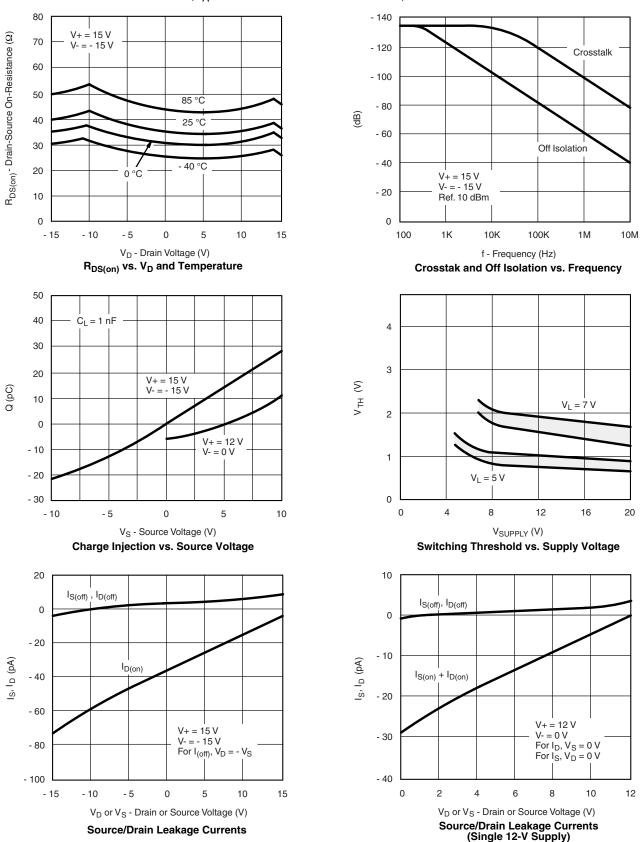
Notes:

- a. Room = 25 °C, Full = as determined by the operating temperature suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. Guaranteed by design, not subject to production test.
- e. V_{IN} = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

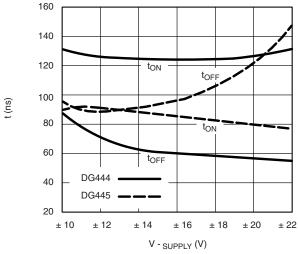
VISHAY

TYPICAL CHARACTERISTICS ($T_A = 25$ °C, unless otherwise noted)

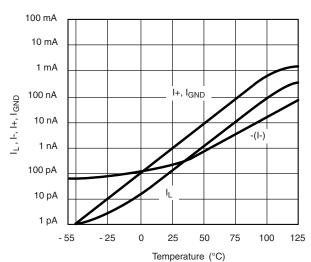




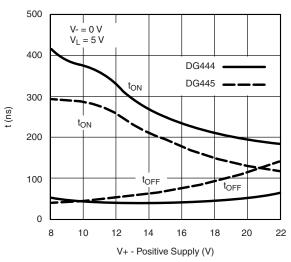
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



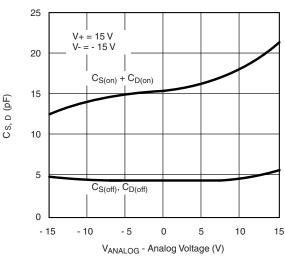
Switching Time vs. Power Supply Voltage



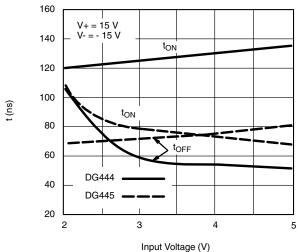
Supply Current vs. Temperature



Switching Times vs. Power Supply Voltage



Source/Drain Capacitance vs. Analog Voltage



Switching Time vs. Input Voltage

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SCHEMATIC DIAGRAM Typical Channel

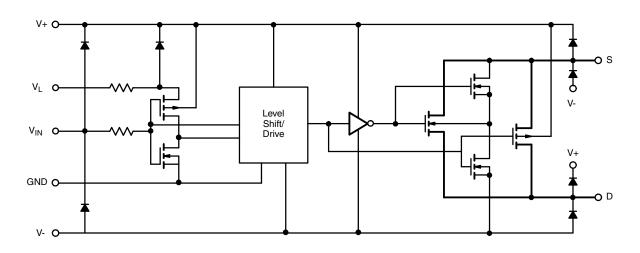


Figure 1.

TEST CIRCUITS

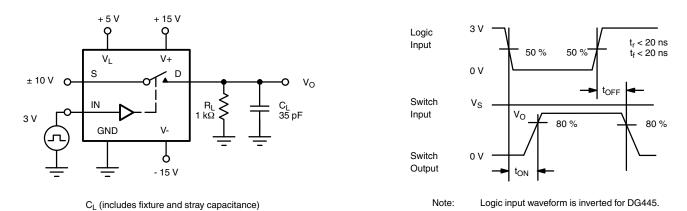


Figure 2. Switching Time

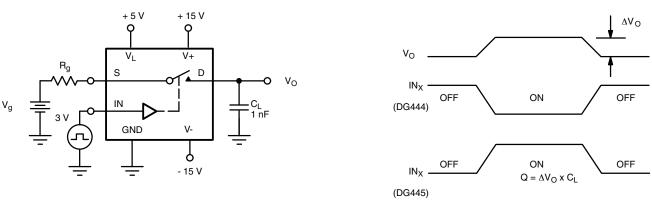


Figure 3. Charge Injection



TEST CIRCUITS

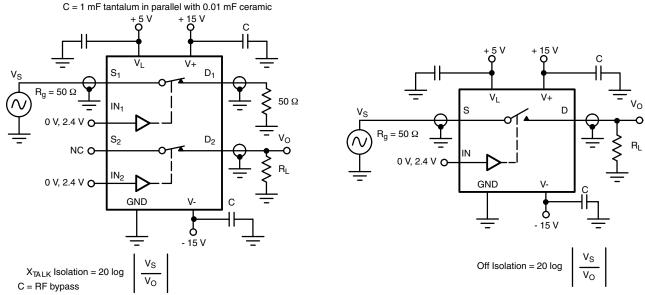


Figure 4. Crosstalk

Figure 5. Off Isolation

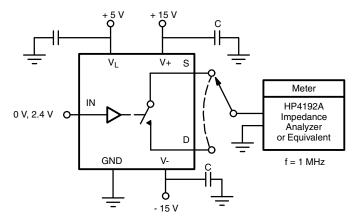


Figure 6. Source/Drain Capacitances

APPLICATIONS

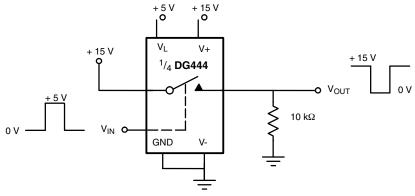


Figure 7. Level Shifter

APPLICATIONS

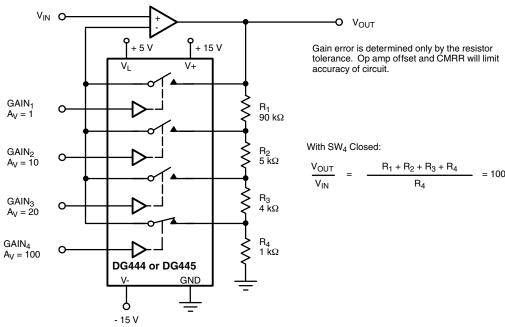


Figure 8. Precision-Weighted Resistor Programmable-Gain Amplifier

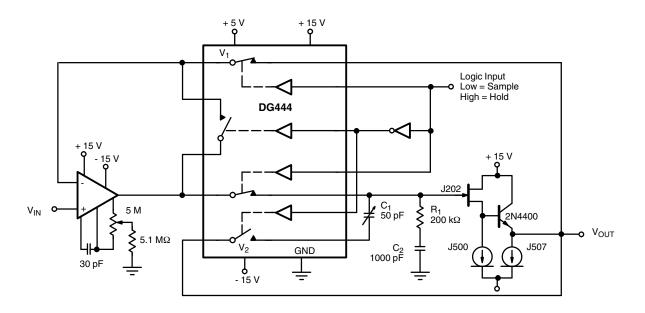


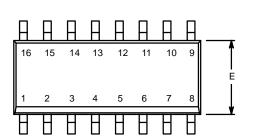
Figure 9. Precision Sample-and-Hold

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?70054.





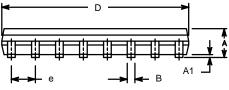
SOIC (NARROW): 16-LEAD JEDEC Part Number: MS-012

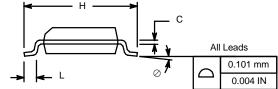


	MILLIMETERS		INC	HES		
Dim	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.38	0.51	0.015	0.020		
С	0.18	0.23	0.007	0.009		
D	9.80	10.00	0.385	0.393		
E	3.80	4.00	0.149	0.157		
е	1.27	BSC	0.050 BSC			
Н	5.80	6.20	0.228	0.244		
L	0.50	0.93	0.020	0.037		
0	0°	8°	0°	8°		
FCN: S-03946—Rev F 09-Jul-01						

ECN: S-03946—Rev. F, 09-Jul-01

DWG: 5300

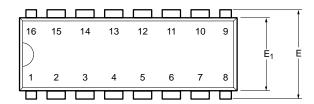


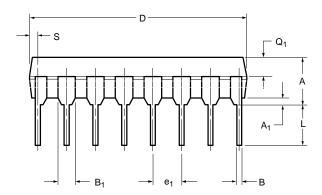


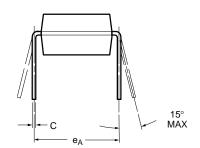
www.vishay.com 02-Jul-01



PDIP: 16-LEAD





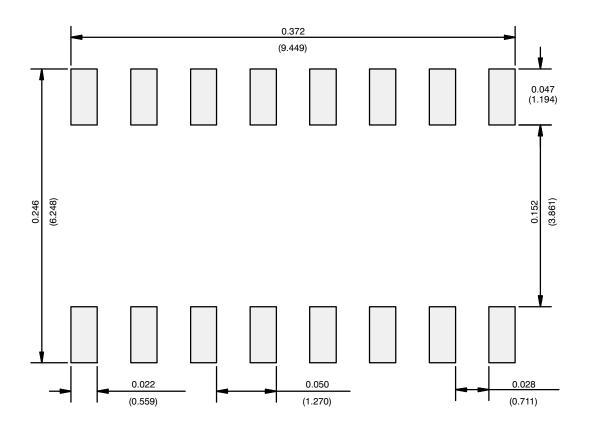


	MILLIN	IETERS	INC	HES	
Dim	Min	Max	Min	Max	
Α	3.81	5.08	0.150	0.200	
A ₁	0.38	1.27	0.015	0.050	
В	0.38	0.51	0.015	0.020	
B ₁	0.89	1.65	0.035	0.065	
С	0.20	0.30	0.008	0.012	
D	18.93	21.33	0.745	0.840	
E	7.62	8.26	0.300	0.325	
E ₁	5.59	7.11	0.220	0.280	
e ₁	2.29	2.79	0.090	0.110	
e _A	7.37	7.87	0.290	0.310	
L	2.79	3.81	0.110	0.150	
Q ₁	1.27	2.03	0.050	0.080	
S	0.38	1.52	.015	0.060	
ECN: S-03946—Rev. D, 09-Jul-01 DWG: 5482					

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RECOMMENDED MINIMUM PADS FOR SO-16



Recommended Minimum Pads Dimensions in Inches/(mm)

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Revision: 02-Oct-12 Document Number: 91000

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PI5A4157ZUEX PI5A3166TAEX FSA634UCX TC4066BP(N,F) DG302BDJ-E3 PI5A100QEX HV2605FG-G HV2301FG-G
RS2117YUTQK10 RS2118YUTQK10 RS2227XUTQK10 ADG452BRZ-REEL7 MAX4066ESD+ MAX391CPE+ MAX4730EXT+T
MAX314CPE+ BU4066BCFV-E2 MAX313CPE+ BU4S66G2-TR NLASB3157MTR2G TS3A4751PWR NLAST4599DFT2G
NLAST4599DTT1G DG300BDJ-E3 DG2503DB-T2-GE1 TC4W53FU(TE12L,F) 74HC2G66DC.125 ADG619BRMZ-REEL
LTC201ACN#PBF 74LV4066DB,118 FSA2275AUMX DIO1500WL12 ADG742BKSZ-REEL7 DIO1269LP10 DG307BDJ-E3